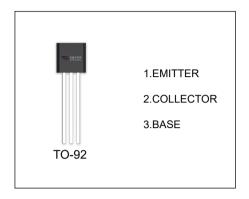


# 3DD13001B TRANSISTOR (NPN)

### **FEATURE**

• power switching applications



#### **ORDERING INFORMATION**

| Part Number  | Package | Packing Method | Pack Quantity |  |
|--------------|---------|----------------|---------------|--|
| 3DD13001B    | TO-92   | Bulk           | 1000pcs/Bag   |  |
| 3DD13001B-TA | TO-92   | Таре           | 2000pcs/Box   |  |

## MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

| Symbol                           | Parameter  | Value   | Unit |
|----------------------------------|--|---------|------|
| V <sub>CBO</sub>                 | Collector -Base Voltage                          | 600     | V    |
| V <sub>CEO</sub>                 | Collector-Emitter Voltage                        | 420     | V    |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                             | 7       | V    |
| Ic                               | Collector Current -Continuous                    | 0.2     | Α    |
| Pc                               | Collector Power Dissipation                      | 0.75    | W    |
| T <sub>J</sub> ,T <sub>stg</sub> | Operation Junction and Storage Temperature Range | -55~150 | °C   |



# $T_a$ =25 $^{\circ}$ C unless otherwise specified

| Parameter                            | Symbol               | Test conditions   | Min | Тур | Max | Unit |
|--------------------------------------|----------------------|---|-----|-----|-----|------|
| Collector-base breakdown voltage     | V <sub>(BR)CBO</sub> | I <sub>C</sub> = 100μA , I <sub>E</sub> =0                    | 600 |     |     | V    |
| Collector-emitter breakdown voltage  | V <sub>(BR)CEO</sub> | I <sub>C</sub> = 1mA , I <sub>B</sub> =0                      | 400 |     |     | V    |
| Emitter-base breakdown voltage       | V <sub>(BR)EBO</sub> | I <sub>E</sub> = 100μA, I <sub>C</sub> =0                     | 7   |     |     | V    |
| Collector cut-off current            | I <sub>CBO</sub>     | V <sub>CB</sub> = 600V , I <sub>E</sub> =0                    |     |     | 100 | μА   |
| Collector cut-off current            | I <sub>CEO</sub>     | V <sub>CE</sub> = 400V, I <sub>B</sub> =0                     |     |     | 200 | μА   |
| Emitter cut-off current              | I <sub>EBO</sub>     | V <sub>EB</sub> =7V, I <sub>C</sub> =0                        |     |     | 100 | μА   |
|                                      | h <sub>FE(1)</sub>   | V <sub>CE</sub> = 20V, I <sub>C</sub> = 20mA                  | 14  |     | 29  |      |
| DC current gain                      | h <sub>FE(2)</sub>   | V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.25 mA               | 5   |     |     |      |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> = 50mA, I <sub>B</sub> = 10 mA                 |     |     | 0.5 | V    |
| Base-emitter saturation voltage      | V <sub>BE(sat)</sub> | I <sub>C</sub> = 50 mA, I <sub>B</sub> = 10mA                 |     |     | 1.2 | V    |
| Transition frequency                 | f <sub>T</sub>       | V <sub>CE</sub> = 20V, I <sub>C</sub> =20mA<br>f = 1MHz       | 8   |     |     | MHz  |
| Fall time                            | t <sub>f</sub>       | I <sub>C</sub> =50mA, I <sub>B1</sub> =-I <sub>B2</sub> =5mA, |     |     | 0.3 | μs   |
| Storage time                         | ts                   | V <sub>CC</sub> =45V  |     |     | 1.5 | μs   |

# **CLASSIFICATION OF hfE(1)**

| Range | 14-17 | 17-20 | 20-23 | 23-26 | 26-29 |
|-------|-------|-------|-------|-------|-------|
|-------|-------|-------|-------|-------|-------|